

# iscN-Channel MOSFET Transistor

### TK5A53D, ITK5A53D

#### • FEATURES

• Low drain-source on-resistance:

RDS(on) =  $1.2\Omega$  (typ.)

• Enhancement mode:

Vth = 2.4 to 4.4V (VDS = 10 V, ID=1.0mA)

- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRITION

Switching Voltage Regulators

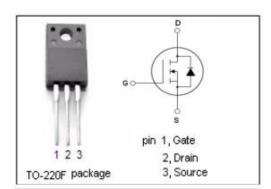


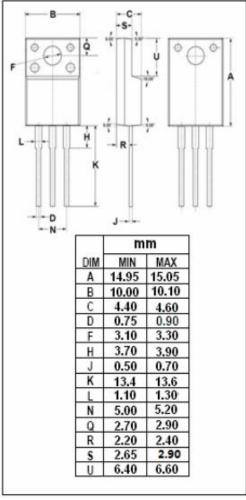
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	525	V
V <sub>GS</sub>	Gate-Source Voltage	±30	V
I <sub>D</sub>	Drain Current-Continuous	5	А
I <sub>DM</sub>	Drain Current-Single Pulsed	20	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	35	W
Tj	Max. Operating Junction Temperature	150	${\mathbb C}$
T <sub>stg</sub>	Storage Temperature	-55~150	°C

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	3.57	°C/W
Rth(ch-a)	Channel-to-ambient thermal resistance		°C/W







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 10mA	525			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =1.0mA	2.4		4.4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =2.5A		1200	1500	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±1	μ <b>А</b>
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =525V; V <sub>GS</sub> = 0V			10	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>DR</sub> =5A, V <sub>GS</sub> = 0 V			1.7	V

#### **NOTICE:**

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